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CD4051B-Q1, CD4053B-Q1

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CD405xB-Q1 CMOS Single 8-Channel Analog Multiplexer/Demultiplexer with Logic-Level Conversion

1 Features

- AEC-Q100 Qualified for Automotive Applications
 Temperature Grade 1: -45°C To +125°C, T_A
- Wide Range of Digital and Analog Signal Levels
 - Digital: 3 V to 20 V
 - Analog: ≤ 20 V_{P-P}
- Low ON Resistance,125 Ω (Typical) Over 15 V_{P-P} Signal Input Range for V_{DD} – V_{EE} = 18 V
- High OFF Resistance, Channel Leakage of ±100 pA (Typical) at V_{DD} - V_{EE} = 18 V
- Logic-Level Conversion for Digital Addressing Signals of 3 V to 20 V ($V_{DD} - V_{SS} = 3$ V to 20 V) to Switch Analog Signals to 20 V_{P-P} ($V_{DD} - V_{EE} =$ 20 V) Matched Switch Characteristics, $r_{ON} = 5 \Omega$ (Typical) for $V_{DD} - V_{EE} = 15$ V Very Low Quiescent Power Dissipation Under All Digital-Control Input and Supply Conditions, 0.2 μ W (Typical) at $V_{DD} - V_{SS} = V_{DD} - V_{EE} = 10$ V
- · Binary Address Decoding on Chip
- 5 V, 10 V, and 15 V Parametric Ratings
- 100% Tested for Quiescent Current at 20 V
- Maximum Input Current of 1 μA at 18 V Over Full Package Temperature Range, 100 nA at 18 V and 25°C
- Break-Before-Make Switching Eliminates Channel
 Overlap

2 Applications

- Analog and Digital Multiplexing and Demultiplexing
- A/D and D/A Conversion
- Signal Gating
- Factory Automation
- Televisions
- Appliances
- Consumer Audio
- Programmable Logic Circuits
- Sensors

3 Description

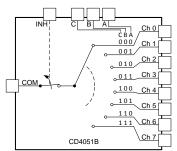
The CD405xB-Q1 analog multiplexers and demuliplexers are digitally-controlled analog switches having low ON impedance and very low OFF leakage current. These multiplexer circuits dissipate extremely low quiescent power over the full $V_{DD} - V_{SS}$ and $V_{DD} - V_{EE}$ supply-voltage ranges, independent of the logic state of the control signals.

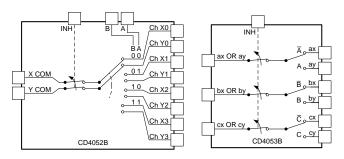
Device	Information ⁽¹	I)
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PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SOIC (D) (16)	9.90 mm × 3.91 mm		
CD405xB	TSSOP (PW) (16)	5.00 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Functional Diagrams of CD405xB-Q1





2

Table of Contents

9

13

1	Feat	tures	1
2	Арр	lications	1
3	Des	cription	1
4	Rev	ision History	2
5	Pin	Configuration and Functions	3
6	Spe	cifications	5
	6.1	Absolute Maximum Ratings	5
	6.2	ESD Ratings	5
	6.3	Recommended Operating Conditions	5
	6.4	Thermal Information	5
	6.5	Electrical Characteristics	6
	6.6	AC Performance Characteristics	8
	6.7	Typical Characteristics	9
7	Para	ameter Measurement Information	10
8	Deta	ailed Description	14
	8.1	Overview	14
	8.2	Functional Block Diagrams	14
	8.3	Feature Description	15

4 Revision History

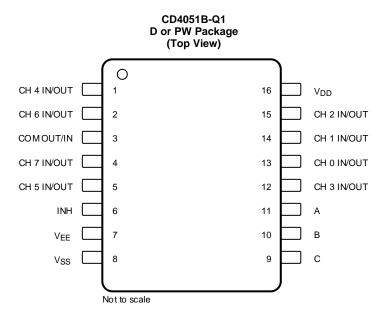
Cł	hanges from Revision A (January 2008) to Revision B	Page
•	Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	
•	Deleted part number CD4052B-Q1 from the data sheets	1

8.4 Device Functional Modes...... 16 Application and Implementation 17 9.1 Application Information..... 17 9.2 Typical Application 17 10 Power Supply Recommendations 18 11.1 Layout Guidelines 19 11.2 Layout Example 19 12 Device and Documentation Support 20 12.1 Documentation Support 20 12.2 Related Links 20 Receiving Notification of Documentation Updates 20 12.3 12.4 Community Resources...... 20 12.5 Trademarks 20 12.6 Electrostatic Discharge Caution 20 12.7 Glossary 20 Mechanical, Packaging, and Orderable Information 20

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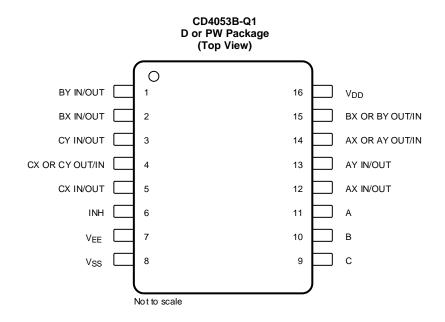
5 Pin Configuration and Functions



Pin Functions CD4051B-Q1

	PIN	I/O	DESCRIPTION			
NO.	NAME	1/0	DESCRIPTION			
1	CH 4 IN/OUT	I/O	Channel 4 in/out			
2	CH 6 IN/OUT	I/O	Channel 6 in/out			
3	COM OUT/IN	I/O	Common out/in			
4	CH 7 IN/OUT	I/O	Channel 7 in/out			
5	CH 5 IN/OUT	I/O	Channel 5 in/out			
6	INH	Ι	Disables all channels. See Table 1.			
7	V _{EE}	—	Negative power input			
8	V _{SS}		Ground			
9	С	Ι	Channel select C. See Table 1.			
10	В	Ι	Channel select B. See .			
11	А	Ι	Channel select A. See Table 1.			
12	CH 3 IN/OUT	I/O	Channel 3 in/out			
13	CH 0 IN/OUT	I/O	Channel 0 in/out			
14	CH 1 IN/OUT	I/O	Channel 1 in/out			
15	CH 2 IN/OUT	I/O	Channel 2 in/out			
16	V _{DD}		Positive power input			





Pin Functions CD4053B-Q1

	PIN	1/0	DESCRIPTION			
NO.	NAME	1/0	DESCRIPTION			
1	BY IN/OUT	I/O	B channel Y in/out			
2	BX IN/OUT	I/O	B channel X in/out			
3	CY IN/OUT	I/O	C channel Y in/out			
4	CX OR CY OUT/IN	I/O	C common out/in			
5	CX IN/OUT	I/O	C channel X in/out			
6	INH	I	Disables all channels. See Table 1.			
7	V _{EE}	—	Negative power input			
8	V _{SS}	—	Ground			
9	С	I	Channel select C. See Table 1.			
10	В	Ι	Channel select B. See Table 1.			
11	A	I	Channel select A. See Table 1.			
12	AX IN/OUT	I/O	A channel X in/out			
13	AY IN/OUT	I/O	A channel Y in/out			
14	AX OR AY OUT/IN	I/O	A common out/in			
15	BX OR BY OUT/IN	I/O	B common out/in			
16	V _{DD}	—	Positive power input			



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
	Supply Voltage	V+ to V-, Voltages Referenced to V _{SS} Terminal	-0.5	20	V
	DC Input Voltage		-0.5	V _{DD} + 0.5	V
	DC Input Current	Any One Input	-10	10	mA
T _{JMAX1}	Maximum junction tempera	iture, ceramic package		175	°C
T _{JMAX2}	Maximum junction tempera	iture, plastic package		150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
CD405	1B-Q1 in PDIP, CDIP, SOIC, SC	P, TSSOP Packages		
V _(ESD) Ele	Electrostatia discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD Classification Level 2	±3000	V
	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-011 CDM ESD Classification Level C6	±2000	V
CD405	3B-Q1 in PDIP, CDIP, SOP and	TSSOP Packages		
V		Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD Classification Level 2	±2500	
V(ESD)	/(ESD) Electrostatic discharge	Charged-device model (CDM), per AEC Q100-011 CDM ESD Classification Level C6	±1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Temperature Range	-55	125	°C

6.4 Thermal Information

		CD405	5xB-Q1	
	THERMAL METRIC ⁽¹⁾	D	PW	UNIT
		16 Pins	16 Pins	
R_{\thetaJA}	Junction-to-ambient thermal resistance	86.7	108	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	47.3		°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	45.3		°C/W
ΨJT	Junction-to-top characterization parameter	12.1		°C/W
Ψјв	Junction-to-board characterization parameter	44.9		°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A		°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

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6.5 Electrical Characteristics

over operating free-air temperature range, $V_{SUPPLY} = \pm 5$ V, and $R_L = 100 \Omega$, (unless otherwise noted)⁽¹⁾

	PARAMETER		TES		NS		MIN	TYP	MAX	UNIT
		V _{IS} (V)	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	TEMP				
SIGNAL INPUTS (V	/ _{IS}) AND OUTPUTS (V _{OS})		-	1						
						–55°C			5	
						–40°C			5	
					5	25°C		0.04	5	
						85°C			150	
						125°C			150	
Quiescent Device Current, I _{DD} Max					–55°C			10		
					-40°C			10		
				10	25°C		0.04	10		
					85°C			300		
					125°C			300		
ulescent Device C	urrent, I _{DD} Max					–55°C			20	μA
						-40°C			20	
					15	25°C		0.04	20	
						85°C			600	
						125°C			600	
						–55°C			100	
						-40°C			100	
					20	25°C		0.08	100	
						85°C			3000	
						125°C			3000	
						–55°C			800	
				-	-40°C			850		
		0	0	5	25°C		470	1050		
					-	85°C			1200	
					-	125°C			1300	
						–55°C			310	
					-	-40°C			300	
rain to Source ON	Resistance r _{on} Max		0	0	10	25°C		180	400	Ω
$\leq V_{IS} \leq V_{DD}$					-	85°C			520	
						125°C			550	
						–55°C			200	
					-	-40°C			210	
			0	0	15	25°C		125	240	
						85°C			300	
						125°C			300	
			0	0	5	-		15		
hange in ON Resi Between Any Two			0	0	10	25°C		10		Ω
r _{on}	11		0	0	15			5		
			-	-	-	–55°C		-	± 100	
						-40°C				
OFF Channel Leakage Current: Any Channel OFF (Max) or ALL Channels OFF (Common OUT/IN) (Max)			0	0	18	25°C		± 0.01	± 100 ⁽²⁾	nA
			Ŭ	Ŭ		25°C			± 1000 ⁽²⁾	
						125°C				
		5 or 0	-5	0	10.5	85°C			± 300 ⁽³⁾	
N Channel Leaka LL Channels ON (ge Current: Any Channel ON (Max) or Common OUT/IN) (Max)	5 01 0	-5	0	10.5	85°C			± 300 ⁽³⁾	nA
	Input, C _{IS}	5	-5	-5	-5	25°C		5	± 300 ···	
-	CD4051B-Q1		-5	-5	-J	20 0		30		
apacitance	Output, C _{os} CD4051B-Q1 CD4053B-Q1					2500		30		pF
	Feed through, C _{IOS}					25°C		Э		

(1) Peak-to-Peak voltage symmetrical about $(V_{DD} - V_{EE}) / 2$.

(2) Determined by minimum feasible leakage measurement for automatic testing.

(3) Does not apply to Hi-Rel CD4051BF and CD4051BFA3 devices.



Electrical Characteristics (continued)

	DADAMETER	TEST CONDITIONS					MIN	TYP	MAX	UNIT
	PARAMETER	V _{IS} (V)	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	TEMP				
		V _{DD}	$R_L = 200 \ k\Omega$,		5			30	60	
ropagation Del	ay Time (Signal Input to Output)	_	$C_{L} = 50 \text{ pF},$		10	25°C		15	30	ns
		┛┖	t_r , t_f = 20 ns		15			10	20	
ONTROL (AD	DRESS OR INHIBIT), V _C		-							
					-	–55°C		1.5		
					-	-40°C		1.5		
					5	25°C			1.5	
						85°C		1.5		
						125°C		1.5		
					-	–55°C		3		
						-40°C		3		
nput Low Voltag	ge, V _{IL} , Max				10	25°C			3	V
						85°C		3		
						125°C		3		
					–55°C		4			
						–40°C		4		
					15	25°C			4	
		V _{IL} = V _{DD} through 1	V – V			85°C		4		
		kΩ ;	$V_{EE} = V_{SS},$ $R_L = 1 k\Omega \text{ to } N$	/ _{SS} ,		125°C		4		
		V _{IH} = V _{DD} through 1	$I_{IS} < 2 \ \mu A \text{ on } A$ Channels	All OFF	-	–55°C		3.5		
		kΩ	onannoio		-	-40°C		3.5		
					5	25°C	3.5			
						85°C		3.5		
						125°C		3.5		
						–55°C		7		
					10	-40°C		7		v
nput High Volta	ge, V _{IH} , Min					25°C	7			
						85°C		7		_
						125°C		7		
						–55°C		11		-
						-40°C		11		
					15	25°C	11			
						85°C		11		
						125°C		11		
						–55°C		± 0.1		
						–40°C		± 0.1		
nput Current, I _{IN}	، (Max)		V _{IN} = 0, 18		18	25°C		± 10 ⁻⁵	± 0.1	μA
						85°C		± 1		
						125°C		± 1		
			0	0	5			450	720	
Propagation	Address-to-Signal OUT (Channels ON	t _r , t _f = 20 ns,	0	0	10			160	320	
Delay Time	or OFF) (See Figure 9, Figure 10, and Figure 14)	$C_{L} = 50 \text{ pF},$ $R_{L} = 10 \text{ k}\Omega$	0	0	15			120	240	ns
		rς ^L = 10 κΩ	-5	0	5			225	450	
			0	0	5			400	720	
Propagation	Inhibit-to-Signal OUT (Channel	t _r , t _f = 20 ns,	0	0	10			160	320	
Delay Time Turning ON) (See Figure 10)		$C_L = 50 \text{ pF},$ $R_L = 1 \text{ k}\Omega$	0	0	15			120	240	ns
		$R_L = 1 k\Omega$	-10	0	5			200	400	
			0	0	5			200	450	
Propagation	Inhibit-to-Signal OUT (Channel	t _r , t _f = 20	0	0	10			90	210	ns
Delay Time	Turning OFF) (See Figure 16)	ns, C _L = 50 pF,	0	0	15			70	160	
		$R_L = 10 k\Omega$	-10	0	5			130	300	
	ce, C _{IN} (Any Address or Inhibit Input)		-	-	-			5	7.5	pF

over operating free-air temperature range, $V_{SUPPLY} = \pm 5 \text{ V}$, and $R_1 = 100 \Omega$, (unless otherwise noted)⁽¹⁾

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6.6 AC Performance Characteristics

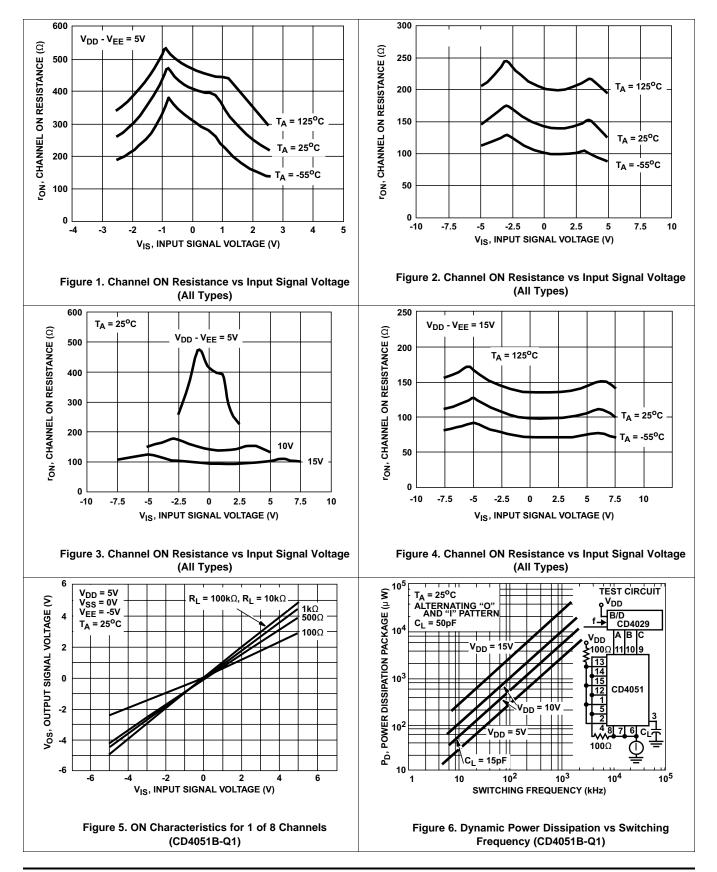
DADAMETER		TVD	UNIT				
PARAMETER	V _{IS} (V)	V _{DD} (V)	R _L (kΩ)		TYP	UNIT	
	5 ⁽¹⁾	10			CD4053B-Q1	30	
Cutoff (-3dB)	500	10	1	V _{OS} at Common OUT/IN	CD4051B-Q1	20	
Frequency Channel ON (Sine Wave Input)	20L	$V_{\rm EE} = V_{\rm SS},$ $og \frac{V_{OS}}{V_{IS}} = -3$	dB	V _{OS} at Any Channel	V _{OS} at Any Channel		
	2 ⁽¹⁾					0.2%	
	3 ⁽¹⁾	5	10			0.3%	-
Total Harmonic Distortion, THD	5 ⁽¹⁾	10	10			0.2%	-
		15		_		0.12%	-
	$V_{EE} = V_{SS}, f_{IS} = 1$	kHz Sine Wav	e				
	5 ⁽¹⁾	10	1	V _{OS} at Common OUT/IN	CD4053B-Q1	8	-
-40dB Feedthrough					CD4051B-Q1	12	-
Frequency (All Channels OFF)	$V_{EE} = V_{SS}$, $20Lc$	$\log \frac{V_{OS}}{V_{IS}} = -4$	0dB	V _{OS} at Any Channel	8	MHz	
	5 ⁽¹⁾	10	1	Between Any two Channe	Between Any two Channels		
–40dB Signal	$V_{EE} = V_{SS},$			Between Sections,	Measured on Common	6	
Crosstalk				CD4052 Only	Measured on Any Channel	10	MHz
Frequency	20 <i>L</i> e	$\log \frac{V_{os}}{V_{vs}} = -4$	0dB	Between Any Two	In Pin 2, Out Pin 14	2.5	-
		V _{IS}		Sections, CD4053 Only	In Pin 15, Out Pin 14	6	
Address-or-Inhibit-to-		10	10 ⁽²⁾			65	
Signal Crosstalk	$V_{EE} = 0, V_{SS} = 0, t$ $V_{CC} = V_{DD} - V_{SS}$ (4)	r , t _f = 20 ns, Square Wave)				65	mV _{PEAK}

Peak-to-Peak voltage symmetrical about (V_{DD} - V_{EE}) / 2. Both ends of channel. (1)

(2)

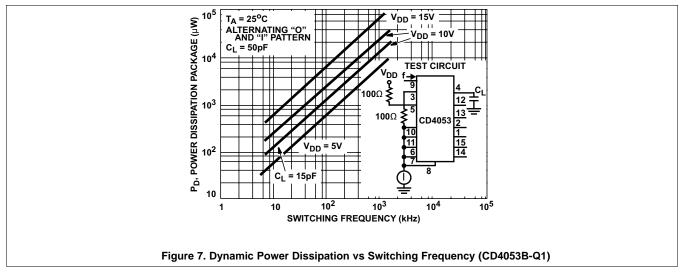


6.7 **Typical Characteristics**

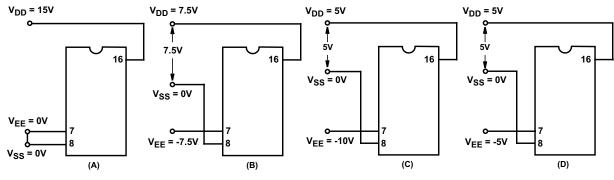




Typical Characteristics (continued)



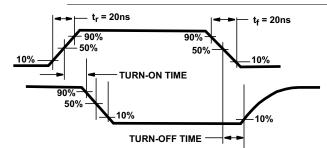
7 Parameter Measurement Information

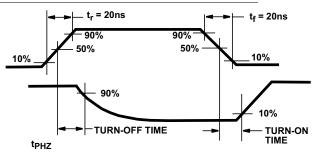


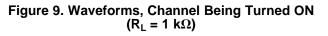


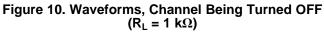
NOTE

The ADDRESS (digital-control inputs) and INHIBIT logic levels are: $0 = V_{SS}$ and $1 = V_{DD}$. The analog signal (through the TG) may swing from V_{EE} to V_{DD} .



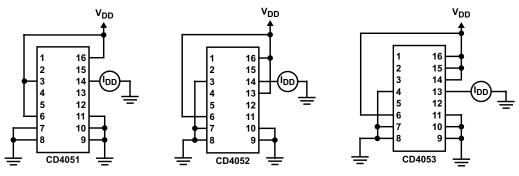








Parameter Measurement Information (continued)





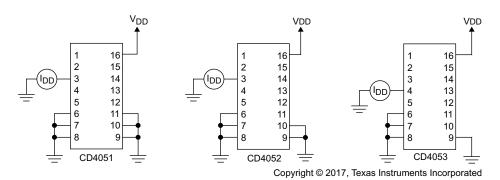


Figure 12. On Channel Leakage Current - Any Channel On

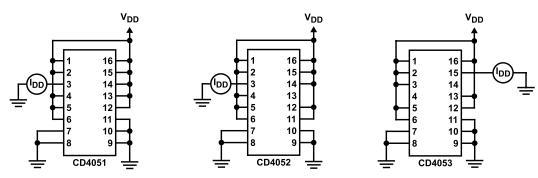
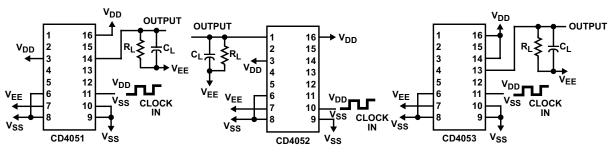
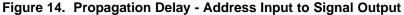


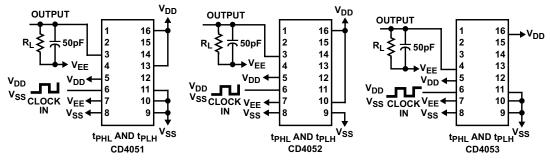
Figure 13. OFF Channel Leakage Current - All Channels OFF

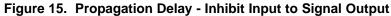


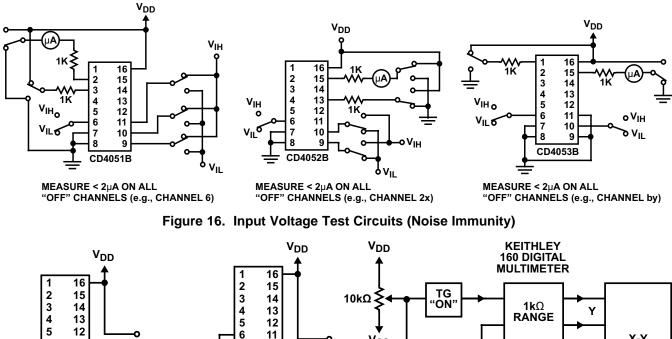


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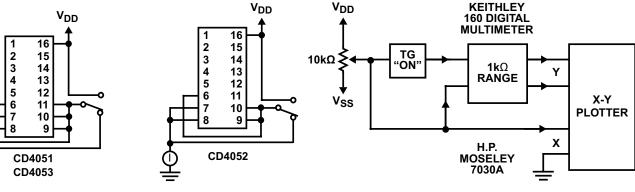


Figure 17. Quiescent Device Current

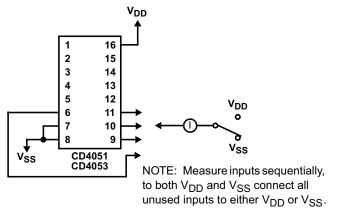




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Parameter Measurement Information (continued)



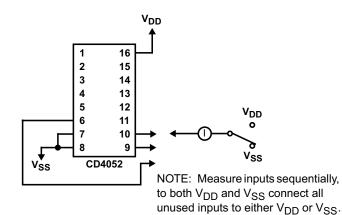
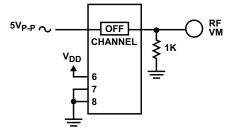


Figure 19. Input Current



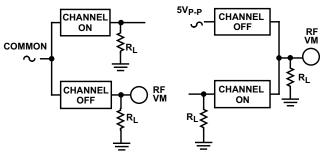


Figure 21. Crosstalk Between Any Two Channels (All Types)

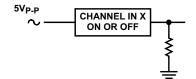


Figure 20. Feedthrough (All Types)

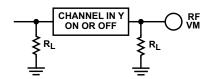


Figure 22. Crosstalk Between Duals or Triplets (CD4053B-Q1)

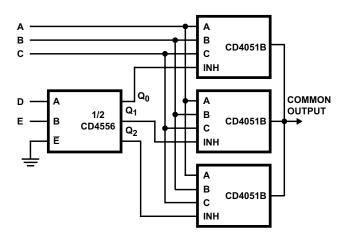


Figure 23. 24-to-1 MUX Addressing



8 Detailed Description

8.1 Overview

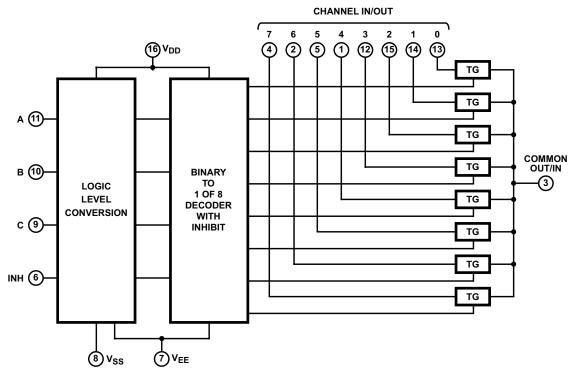
The CD4051B-Q1and CD4053B-Q1analog multiplexers are digitally-controlled analog switches having low ON impedance and very low OFF leakage current. Control of analog signals up to 20 V_{P-P} can be achieved by digital signal amplitudes of 4.5 V to 20 V (if V_{DD} - V_{SS} = 3 V, a V_{DD} - V_{EE} of up to 13 V can be controlled; for V_{DD} - V_{EE} level differences above 13 V, a V_{DD} - V_{SS} of at least 4.5 V is required). For example, if V_{DD} = +4.5 V, V_{SS} = 0 V, and V_{EE} = -13.5 V, analog signals from -13.5 V to +4.5 V can be controlled by digital inputs of 0 V to 5 V. These multiplexer circuits dissipate extremely low quiescent power over the full V_{DD} - V_{SS} and V_{DD} - V_{EE} supply-voltage ranges, independent of the logic state of the control signals. When a logic 1 is present at the inhibit input terminal, all channels are off.

The CD4051B-Q1 device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

The CD4053B-Q1 device is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole, double-throw configuration.

When these devices are used as demultiplexers, the CHANNEL IN/OUT terminals are the outputs and the COMMON OUT/IN terminals are the inputs.

8.2 Functional Block Diagrams

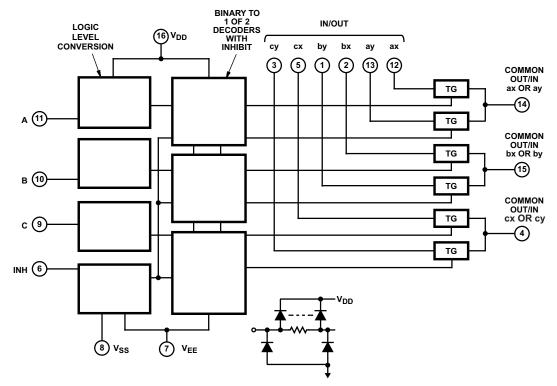


All inputs are protected by standard CMOS protection network.





Functional Block Diagrams (continued)



All inputs are protected by standard CMOS protection network.



8.3 Feature Description

The CD405xB-Q1 line of multiplexers and demultiplexers can accept a wide range of digital and analog signal levels. Digital signals range from 3 V to 20 V, and analog signals are accepted at levels \leq 20 V. They have low ON resistance, typically 125 Ω over 15 V_{P-P} signal input range for V_{DD} - V_{EE} = 18 V. This allows for very little signal loss through the switch. Matched switch characteristics are typically r_{ON} = 5 Ω for V_{DD} - V_{EE} = 15 V.

The CD405xB-Q1 devices also have high OFF resistance, which keeps from wasting power when the switch is in the OFF position, with typical channel leakage of ±100 pA at $V_{DD} - V_{EE} = 18$ V. Very low quiescent power dissipation under all digital-control input and supply conditions, typically 0.2 µW at $V_{DD} - V_{SS} = V_{DD} - V_{EE} = 10$ V keeps power consumption total very low. All devices have been 100% tested for quiescent current at 20 V with maximum input current of 1 µA at 18 V over the full package temperature range, and only 100 nA at 18 V and 25°C.

Logic-level conversion for digital addressing signals of 3 V to 20 V ($V_{DD} - V_{SS} = 3$ V to 20 V) to switch analog signals to 20 V_{P-P} ($V_{DD} - V_{EE} = 20$ V). Binary address decoding on chip makes channel selection easy. When channels are changed, a break-before-make system eliminates channel overlap.

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8.4 Device Functional Modes

	IN			
INHIBIT	С	В	Α	ON CHANNEL(S)
CD4051B-Q1				
L	L	L	L	0
L	L	L	Н	1
L	L	Н	L	2
L	L	Н	Н	3
L	Н	L	L	4
L	Н	L	Н	5
L	Н	Н	L	6
L	Н	Н	Н	7
Н	Х	Х	Х	None
CD4053B				
L	L	L	L	ay or by or cy
L	Н	Н	Н	ay or by or cy
Н	Х	Х	Х	None

Table 1. Truth Table⁽¹⁾

(1) X = Don't Care



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The CD405xB-Q1 multiplexers and demuliplexers can be used for a wide variety of applications.

9.2 Typical Application

One application of the CD4051B-Q1 is to use it in conjunction with a microcontroller to poll a keypad. Figure 26 shows the basic schematic for such a polling system. The microcontroller uses the channel select pins to cycle through the different channels while reading the input to see if a user is pressing any of the keys. This is a very robust setup, allowing for multiple simultaneous key-presses with very little power consumption. It also uses very few pins on the microcontroller. The down side of polling is that the microcontroller must continually scan the keys for a press and can do little else during this process.

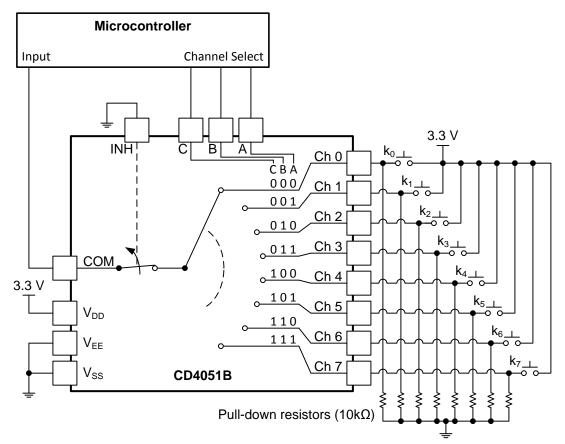


Figure 26. The CD4051B-Q1 Being Used to Help Read Button Presses on a Keypad.

9.2.1 Design Requirements

These devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

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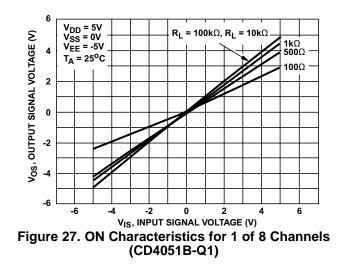
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Typical Application (continued)

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - For switch time specifications, see propagation delay times in *Electrical Characteristics*.
 - Inputs should not be pushed more than 0.5 V above V_{DD} or below V_{EE}.
 - For input voltage level specifications for control inputs, see V_{IH} and V_{IL} in *Electrical Characteristics*.
- 2. Recommended Output Conditions
 - Outputs should not be pulled above V_{DD} or below V_{EE}.
- 3. Input/output current consideration: The CD405xB-Q1 series of parts do not have internal current drive circuitry and thus cannot sink or source current. Any current will be passed through the device.

9.2.3 Application Curve



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Electrical Characteristics*.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F bypass capacitor is recommended. If there are multiple pins labeled V_{CC}, then a 0.01- μ F or 0.022- μ F capacitor is recommended for each V_{CC} because the V_{CC} pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V_{CC} and V_{DD}, a 0.1- μ F bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.



11 Layout

11.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Figure 28 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

11.2 Layout Example

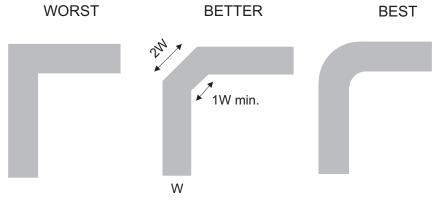


Figure 28. Trace Example

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12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

Implications of Slow or Floating CMOS Inputs, SCBA004

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY					
CD4051B-Q1	Click here	Click here	Click here	Click here	Click here					
CD4053B-Q1	Click here	Click here	Click here	Click here	Click here					

Table 2. Related Links

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.5 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		au	(2)	(6)	(3)		(4/5)	
CD4051BQPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CM051BQ	Samples
CD4051BQPWRQ1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CM051BQ	Samples
CD4053BQM96G4Q1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD4053Q	Samples
CD4053BQM96Q1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD4053Q	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4051B-Q1, CD4053B-Q1 :

• Catalog: CD4051B, CD4053B

• Military: CD4051B-MIL, CD4053B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4051BQPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4051BQPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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PACKAGE MATERIALS INFORMATION

21-Mar-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4051BQPWRG4Q1	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4051BQPWRQ1	TSSOP	PW	16	2000	367.0	367.0	35.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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